



1K x 8 Dual-Port Static RAM

Features

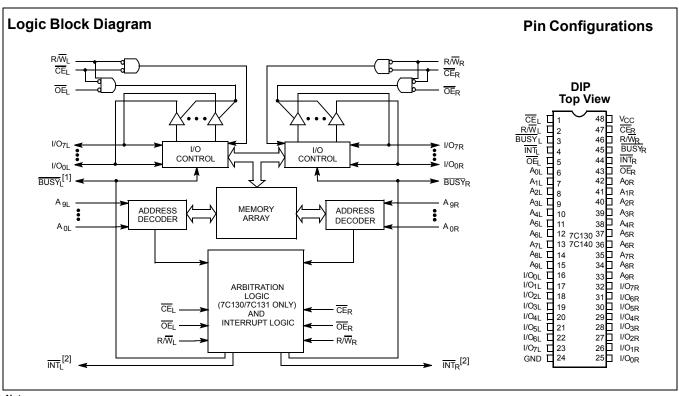
- True Dual-Ported memory cells which allow simultaneous reads of the same memory location
- 1K x 8 organization
- 0.65-micron CMOS for optimum speed/power
- · High-speed access: 15 ns
- Low operating power: I_{CC} = 110 mA (max.)
- Fully asynchronous operation
- · Automatic power-down
- Master CY7C130/CY7C131 easily expands data bus width to 16 or more bits using slave CY7C140/CY7C141
- BUSY output flag on CY7C130/CY7C131; BUSY input on CY7C140/CY7C141
- · INT flag for port-to-port communication
- Available in 48-pin DIP (CY7C130/140), 52-pin PLCC, 52-Pin TQFP.
- · Pb-Free packages available

Functional Description

The CY7C130/CY7C131/CY7C140 and CY7C141 are high-speed CMOS 1K by 8 dual-port static RAMs. Two ports are provided permitting independent access to any location in memory. The CY7C130/ CY7C131 can be utilized as either a standalone 8-bit dual-port static RAM or as a master dual-port RAM in conjunction with the CY7C140/CY7C141 slave dual-port device in systems requiring 16-bit or greater word widths. It is the solution to applications requiring shared or buffered data, such as cache memory for DSP, bit-slice, or multiprocessor designs.

Each port has independent control pins; chip enable (\overline{CE}) , write enable (R/W), and output enable (\overline{OE}) . Two flags are provided on each port, BUSY and INT. BUSY signals that the port is trying to access the same location currently being accessed by the other port. \overline{INT} is an interrupt flag indicating that data has been placed in a unique location (3FF for the left port and 3FE for the right port). An automatic power-down feature is controlled independently on each port by the chip enable (\overline{CE}) pins.

The CY7C130 and CY7C140 are available in 48-pin DIP. The CY7C131 and CY7C141 are available in 52-pin PLCC, 52-pin Pb-free PLCC, 52-pin PQFP and 52-pin Pb-free PQFP.

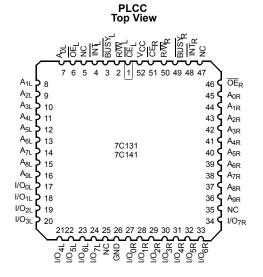


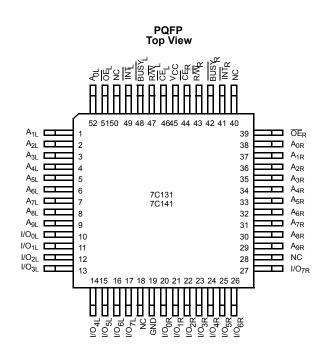
Note

- CY7C130/CY7C131 (Master): <u>BUSY</u> is open drain output and requires pull-up resistor CY7C140/CY7C141 (Slave): BUSY is input.
- 2. Open drain outputs: pull-up resistor required.



Pin Configuration (continued)





Pin Definitions

Left Port	Right Port	Description
CEL	CE _R	Chip Enable
R/\overline{W}_L	R/W _R	Read/Write Enable
ŌĒL	ŌĒ _R	Output Enable
A _{0L} -A _{11/12L}	A _{0R} -A _{11/12R}	Address
I/O _{0L} –I/O _{15/17L}	I/O _{0R} -I/O _{15/17R}	Data Bus Input/Output
ĪNT _L	ĪNT _R	Interrupt Flag
BUSYL	BUSY _R	Busy Flag
V _{CC}		Power
GND		Ground

Selection Guide

		7C131-15 ^[3] 7C141-15	7C131-25 ^[3] 7C141-25	7C130-30 7C131-30 7C140-30 7C141-30	7C130-35 7C131-35 7C140-35 7C141-35	7C130-45 7C131-45 7C140-45 7C141-45	7C130-55 7C131-55 7C140-55 7C141-55	Unit
Maximum Access Time		15	25	30	35	45	55	ns
Maximum Operating	Com'l/Ind	190	170	170	120	120	110	mA
Current	Military				170	170	120	
Maximum Standby	Com'l/Ind	75	65	65	45	45	35	mA
Current	Military				65	65	45	

Shaded areas contain preliminary information.

Note

3. 15 and 25-ns version available only in PLCC/PQFP packages.



Maximum Ratings^[4]

Static Discharge Voltage	. >2001V
(per MIL-STD-883, Method 3015)	
Latch-Up Current	>200 mA

Operating Range

Range	Ambient Temperature	V _{cc}
Commercial	0°C to +70°C	5V ± 10%
Industrial	–40°C to +85°C	5V ± 10%
Military ^[5]	–55°C to +125°C	5V ± 10%

Electrical Characteristics Over the Operating Range^[6]

					1-15 ^[3] 41-15	7C131 7C14	0-30 ^[3] I-25,30 40-30 I-25,30	7C13	0-35,45 1-35,45 0-35,45 1-35,45	7C13	30-55 31-55 40-55 41-55	
Parameter	Description	Test Condition	ns	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Unit
V _{OH}	Output HIGH Voltage	V _{CC} = Min., I _{OH} = -	4.0 mA	2.4		2.4		2.4		2.4		V
V _{OL}	Output LOW	I _{OL} = 4.0 mA			0.4		0.4		0.4		0.4	V
	Voltage	I _{OL} = 16.0 mA ^[7]			0.5		0.5		0.5		0.5	
V _{IH}	Input HIGH Voltage			2.2		2.2		2.2		2.2		V
V _{IL}	Input LOW Voltage				0.8		0.8		0.8		0.8	V
I _{IX}	Input Leakage Current	$GND \leq V_I \leq V_CC$		– 5	+5	– 5	+5	-5	+5	– 5	+5	μА
I _{OZ}	Output Leakage Current	$\begin{array}{l} \text{GND} \leq \text{V}_{\text{O}} \leq \text{V}_{\text{CC}}, \\ \text{Output Disabled} \end{array}$		– 5	+5	– 5	+5	- 5	+5	- 5	+5	μА
I _{OS}	Output Short Circuit Current ^[8, 9]	V _{CC} = Max., V _{OUT} = GND			-350		-350		-350		-350	mA
I _{CC}	V _{CC} Operating	CE = V _{IL} ,	Com'l		190		170		120		110	mA
	Supply Current	Outputs Open, f = f _{MAX} ^[10]	Mil						170		120	•
I _{SB1}	Standby Current	CE _L and CE _R > V _{IH} , f = f _{MAX} [10]	Com'l		75		65		45		35	mA
	Both Ports, TTL Inputs	V_{IH} , $f = f_{MAX}^{[10]}$	Mil						65		45	
I _{SB2}	Standby Current	\overline{CE}_L or $\overline{CE}_R \ge V_{IH}$,	Com'l		135		115		90		75	mA
	One Port, TTL Inputs	Active Port Outputs Open, f = f _{MAX} ^[10]	Mil						115		90	
I _{SB3}	Standby Current	Both Ports CE _L and	Com'l		15		15		15		15	mA
	Both Ports, CMOS Inputs	$CE_R \ge V_{CC} - 0.2V,$ $V_{IN} \ge V_{CC} - 0.2V$ or $V_{IN} \le 0.2V, f = 0$	Mil						15		15	

Shaded areas contain preliminary information.

Note:

- 4. The Voltage on any input or I/O pin cannot exceed the power pin during power-up.
- 5. T_A is the "instant on" case temperature
- 6. See the last page of this specification for Group A subgroup testing information.
- BUSY and INT pins only.
- 8. Duration of the short circuit should not exceed 30 seconds.
- 9. This parameter is guaranteed but not tested.
- 10. At f = f_{MAX}, address and data inputs are cycling at the maximum frequency of read cycle of 1/t_{RC} and using AC Test Waveforms input levels of GND to 3V.



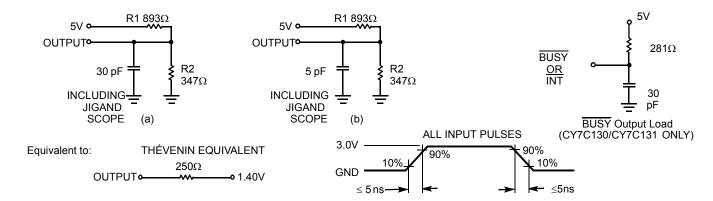
Electrical Characteristics Over the Operating Range^[6] (continued)

					1-15 ^[3] I1-15	7C130-30 ^[3] 7C131-25,30 7C140-30 7C141-25,30		7C130-35,45 7C131-35,45 7C140-35,45 7C141-35,45		7C131-55 7C140-55		
Parameter	Description	Test Condition	ns	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Unit
I _{SB4}	Standby Current	One Port CE _L or	Com'l		125		105		85		70	mA
	One Port, CMOS Inputs	$\begin{split} & \text{CE}_{\text{R}} \geq \text{V}_{\text{CC}} - 0.2\text{V}, \\ & \text{V}_{\text{IN}} \geq \text{V}_{\text{CC}} - 0.2\text{V} \\ & \text{or V}_{\text{IN}} \leq 0.2\text{V}, \\ & \text{Active Port Outputs} \\ & \text{Open}, \\ & \text{f} = f_{\text{MAX}}^{[10]} \end{split}$	Mil						105		85	

Capacitance^[9]

Parameter	Description	Test Conditions	Max.	Unit
C _{IN}	Input Capacitance	$T_A = 25^{\circ}C, f = 1 \text{ MHz},$	15	pF
C _{OUT}	Output Capacitance	$V_{CC} = 5.0V$	10	pF

AC Test Loads and Waveforms



[+] Feedback



Switching Characteristics Over the Operating Range^[6, 11]

			1-15 ^[3] 41-15	7C1: 7C1	0-25 ^[3] 31-25 40-25 41-25	7C1: 7C1	30-30 31-30 40-30 41-30	
Parameter	Description	Min.	Max.	Min.	Max.	Min.	Max.	Unit
READ CYCL	Ē	·						
t _{RC}	Read Cycle Time	15		25		30		ns
t _{AA}	Address to Data Valid ^[12]		15		25		30	ns
t _{OHA}	Data Hold from Address Change	0		0		0		ns
t _{ACE}	CE LOW to Data Valid ^[12]		15		25		30	ns
t _{DOE}	OE LOW to Data Valid ^[12]		10		15		20	ns
t _{LZOE}	OE LOW to Low Z ^[9, 13, 14]	3		3		3		ns
t _{HZOE}	OE HIGH to High Z ^[9, 13, 14]		10		15		15	ns
t _{LZCE}	CE LOW to Low Z ^[9, 13, 14]	3		5		5		ns
t _{HZCE}	CE HIGH to High Z ^[9, 13, 14]		10		15		15	ns
t _{PU}	CE LOW to Power-Up ^[9]	0		0		0		ns
t _{PD}	CE HIGH to Power-Down ^[9]		15		25		25	ns
WRITE CYC	LE ^[15]	<u>'</u>	I	1				.1
t _{WC}	Write Cycle Time	15		25		30		ns
t _{SCE}	CE LOW to Write End	12		20		25		ns
t _{AW}	Address Set-Up to Write End	12		20		25		ns
t _{HA}	Address Hold from Write End	2		2		2		ns
t _{SA}	Address Set-Up to Write Start	0		0		0		ns
t _{PWE}	R/W Pulse Width	12		15		25		ns
t _{SD}	Data Set-Up to Write End	10		15		15		ns
t _{HD}	Data Hold from Write End	0		0		0		ns
t _{HZWE}	R/W LOW to High Z ^[14]		10		15		15	ns
t _{LZWE}	R/W HIGH to Low Z ^[14]	0		0		0		ns
	ntain preliminary information.			1	1	1	1	

Shaded areas contain preliminary information.

^{11.} Test conditions assume signal transition times of 5 ns or less, timing reference levels of 1.5V, input pulse levels of 0 to 3.0V and output loading of the specified I_{OL}/I_{OH,} and 30-pF load capacitance.

12. AC Test Conditions use V_{OH} = 1.6V and V_{OL} = 1.4V.

^{12.} AC lest Conditions use V_{OH} = 1.6V and V_{OL} = 1.4V.

13. At any given temperature and voltage condition for any given device, t_{HZCE} is less than t_{LZCE} and t_{HZOE} is less than t_{LZOE}.

14. t_{LZCE}, t_{LZWE}, t_{HZOE}, t_{HZOE}, t_{HZCE} and t_{HZWE} are tested with C_L = 5<u>pF</u> as in part (b) <u>of</u> AC Test Loads. Transition is measured ±500 mV from steady state voltage.

15. The internal write time of the memory is defined by the overlap of CS LOW and R/W LOW. Both signals must be low to initiate a write and either signal can terminate a write by going high. The data input set-up and hold timing should be referenced to the rising edge of the signal that terminates the write.



Switching Characteristics Over the Operating Range $^{[6,\ 11]}$ (continued)

			1-15 ^[3] 41-15	7C1: 7C1	0-25 ^[3] 31-25 40-25 41-25	7C1: 7C1:	30-30 31-30 40-30 41-30	
Parameter	Description	Min.	Max.	Min.	Max.	Min.	Max.	Unit
BUSY/INTER	RUPT TIMING							
t _{BLA}	BUSY LOW from Address Match		15		20		20	ns
t _{BHA}	BUSY HIGH from Address Mismatch ^[16]		15		20		20	ns
t _{BLC}	BUSY LOW from CE LOW		15		20		20	ns
t _{BHC}	BUSY HIGH from CE HIGH ^[16]		15		20		20	ns
t _{PS}	Port Set Up for Priority	5		5		5		ns
t _{WB} ^[17]	R/W LOW after BUSY LOW	0		0		0		ns
t _{WH}	R/W HIGH after BUSY HIGH	13		20		30		ns
t _{BDD}	BUSY HIGH to Valid Data		15		25		30	ns
t _{DDD}	Write Data Valid to Read Data Valid		Note 18		Note 18		Note 18	ns
t _{WDD}	Write Pulse to Data Delay		Note 18		Note 18		Note 18	ns
INTERRUPT	TIMING							
t _{WINS}	R/W to INTERRUPT Set Time		15		25		25	ns
t _{EINS}	CE to INTERRUPT Set Time		15		25		25	ns
t _{INS}	Address to INTERRUPT Set Time		15		25		25	ns
t _{OINR}	OE to INTERRUPT Reset Time ^[16]		15		25		25	ns
t _{EINR}	CE to INTERRUPT Reset Time ^[16]		15		25		25	ns
t _{INR}	Address to INTERRUPT Reset Time ^[16]		15		25		25	ns

Shaded areas contain preliminary information.

Switching Characteristics Over the Operating Range^[6,11]

		7C130-35 7C131-35 7C140-35 7C141-35		7C130-45 7C131-45 7C140-45 7C141-45		7C130-55 7C131-55 7C140-55 7C141-55		
Parameter	Description	Min.	Max.	Min.	Max.	Min.	Max.	Unit
READ CYCL	Ē	·						
t _{RC}	Read Cycle Time	35		45		55		ns
t _{AA}	Address to Data Valid ^[12]		35		45		55	ns
t _{OHA}	Data Hold from Address Change	0		0		0		ns
t _{ACE}	CE LOW to Data Valid ^[12]		35		45		55	ns
t _{DOE}	OE LOW to Data Valid ^[12]		20		25		25	ns
t _{LZOE}	OE LOW to Low Z ^[9, 13, 14]	3		3		3		ns
t _{HZOE}	OE HIGH to High Z ^[9, 13, 14]		20		20		25	ns
t _{LZCE}	CE LOW to Low Z ^[9, 13, 14]	5		5		5		ns

^{16.} These parameters are measured from the input signal changing, until the output pin goes to a high-impedance state.

^{17.} CY7C140/CY7C141 only.

^{18. &}lt;u>A write</u> operation on Port A, where Port A has priority, leaves the data on Port B's outputs undisturbed until one access time after one of the following: BUSY on Port B goes HIGH.

<u>Port B's address is toggled.</u>

<u>CE for Port B is toggled.</u>

R/W for Port B is toggled during valid read.



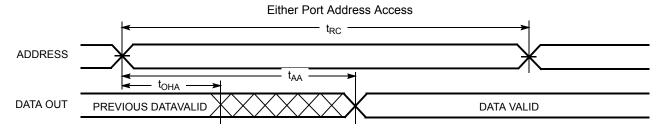
$\textbf{Switching Characteristics} \ \, \text{Over the Operating Range}^{[6,11]} \ \, \text{(continued)}$

		7C13	30-35 31-35 40-35 41-35	7C13 7C13 7C14 7C14	1-45 0-45	7C13	30-55 31-55 40-55 41-55	
Parameter	Description	Min.	Max.	Min.	Max.	Min.	Max.	Unit
t _{HZCE}	CE HIGH to High Z ^[9, 13, 14]		20		20		25	ns
t _{PU}	CE LOW to Power-Up ^[9]	0		0		0		ns
t _{PD}	CE HIGH to Power-Down ^[9]		35		35		35	ns
WRITE CYC	L E ^[15]							
t _{WC}	Write Cycle Time	35		45		55		ns
t _{SCE}	CE LOW to Write End	30		35		40		ns
t _{AW}	Address Set-Up to Write End	30		35		40		ns
t _{HA}	Address Hold from Write End	2		2		2		ns
t _{SA}	Address Set-Up to Write Start	0		0		0		ns
t _{PWE}	R/W Pulse Width	25		30		30		ns
t _{SD}	Data Set-Up to Write End	15		20		20		ns
t _{HD}	Data Hold from Write End	0		0		0		ns
t _{HZWE}	R/\overline{W} LOW to High $Z^{[14]}$		20		20		25	ns
t _{LZWE}	R/\overline{W} HIGH to Low $Z^{[14]}$	0		0		0		ns
BUSY/INTER	RRUPT TIMING							
t _{BLA}	BUSY LOW from Address Match		20		25		30	ns
t _{BHA}	BUSY HIGH from Address Mismatch ^[16]		20		25		30	ns
t _{BLC}	BUSY LOW from CE LOW		20		25		30	ns
t _{BHC}	BUSY HIGH from CE HIGH ^[16]		20		25		30	ns
t _{PS}	Port Set Up for Priority	5		5		5		ns
t _{WB} ^[17]	R/W LOW after BUSY LOW	0		0		0		ns
t _{WH}	R/W HIGH after BUSY HIGH	30		35		35		ns
t _{BDD}	BUSY HIGH to Valid Data		35		45		45	ns
t _{DDD}	Write Data Valid to Read Data Valid		Note 18		Note 18		Note 18	ns
t _{WDD}	Write Pulse to Data Delay		Note 18		Note 18		Note 18	ns
INTERRUPT	TIMING		<u>.</u>		1	1		1
t _{WINS}	R/W to INTERRUPT Set Time		25		35		45	ns
t _{EINS}	CE to INTERRUPT Set Time		25		35		45	ns
t _{INS}	Address to INTERRUPT Set Time		25		35		45	ns
t _{OINR}	OE to INTERRUPT Reset Time ^[16]		25		35		45	ns
t _{EINR}	CE to INTERRUPT Reset Time ^[16]		25		35		45	ns
t _{INR}	Address to INTERRUPT Reset Time ^[16]		25		35		45	ns

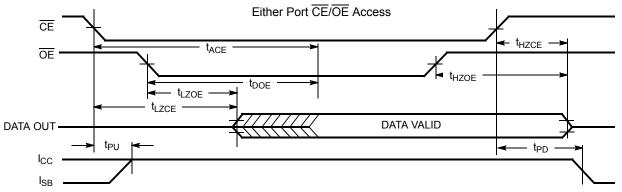


Switching Waveforms

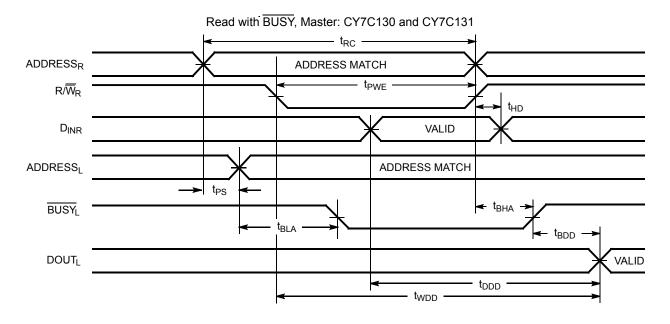
Read Cycle No. 1^[19, 20]



Read Cycle No. 2^[19, 21]



Read Cycle No. 3^[20]

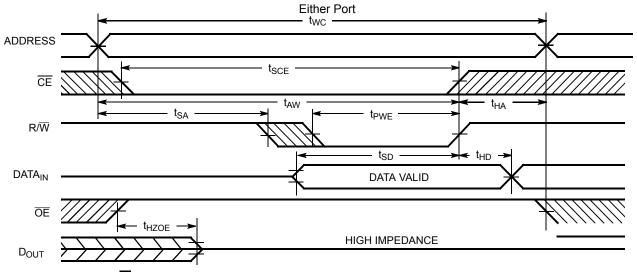


- 19. R/W is HIGH for read cycle.
- 20. Device is continuously selected, $\overline{\text{CE}} = \text{V}_{\text{IL}}$ and $\overline{\text{OE}} = \text{V}_{\text{IL}}$. 21. Address valid prior to or coincident with $\overline{\text{CE}}$ transition LOW.

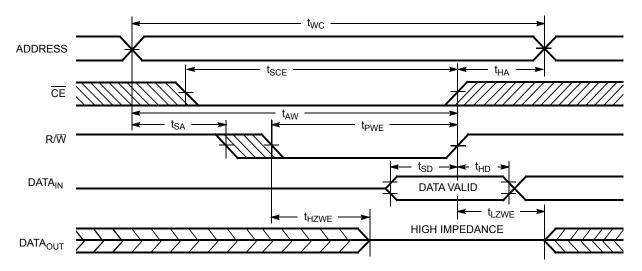
[+] Feedback



Write Cycle No. 1 (OE Three-States Data I/Os—Either Port[15, 22]



Write Cycle No. 2 (R/ \overline{W} Three-States Data I/Os—Either Port)^[16, 23]



Notes:

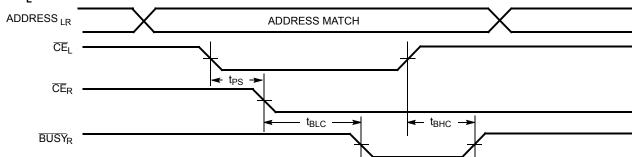
22. If \overline{OE} is LOW during a R/W controlled write cycle, the write pulse width must be the larger of t_{PWE} or $t_{HZWE} + t_{SD}$ to allow the data I/O pins to enter high impedance and for data to be placed on the bus for the required t_{SD} .

23. If the \overline{CE} LOW transition occurs simultaneously with or after the R/W LOW transition, the outputs remain in the high-impedance state.

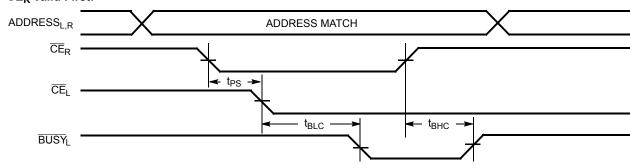


Busy Timing Diagram No. 1 (CE Arbitration)

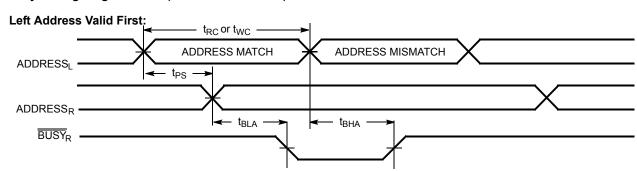
CE_L Valid First:

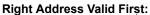


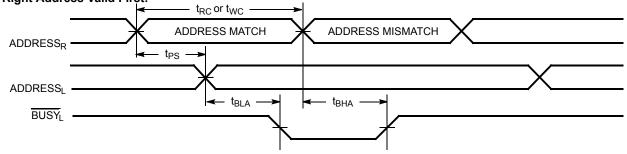
CE_R Valid First:



Busy Timing Diagram No. 2 (Address Arbitration)



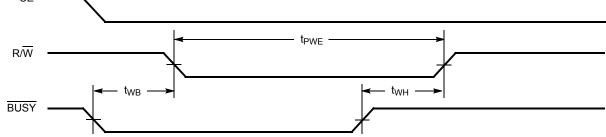






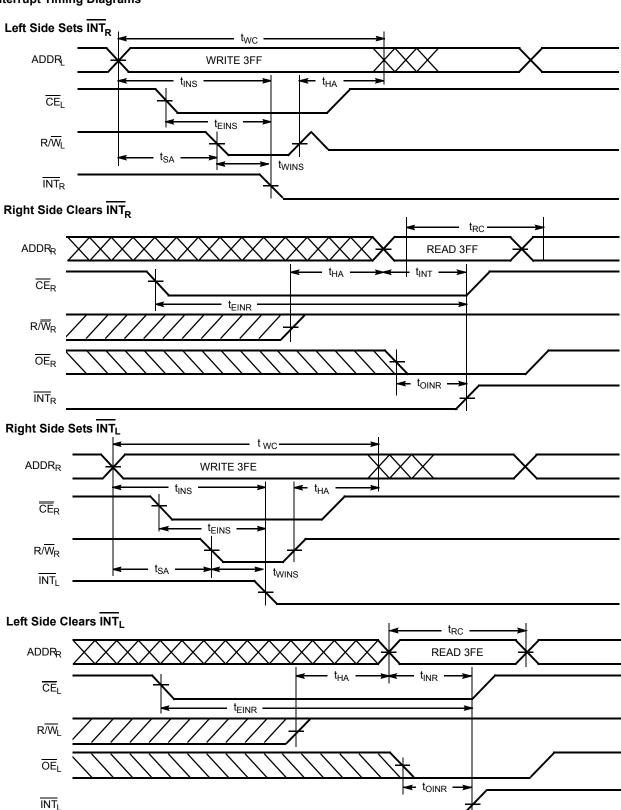
Busy Timing Diagram No. 3

Write with BUSY (Slave:CY7C140/CY7C141)



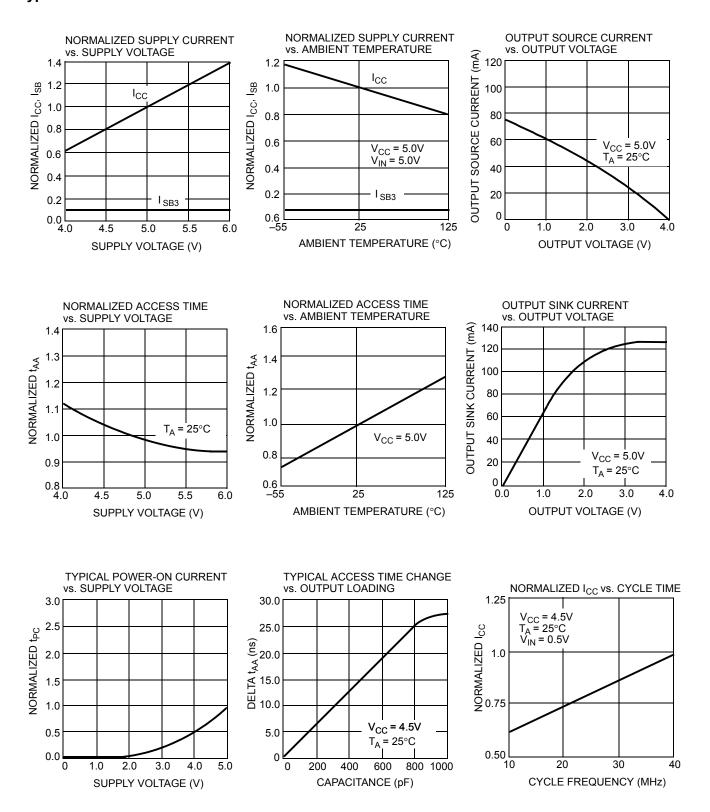


Interrupt Timing Diagrams





Typical DC and AC Characteristics





Ordering Information

Speed (ns)	Ordering Code	Package Name	Package Type	Operating Range
30	CY7C130-30PC	P25	48-Lead (600-Mil) Molded DIP	Commercial
	CY7C130-30PI	P25	48-Lead (600-Mil) Molded DIP	Industrial
35	CY7C130-35PC	P25	48-Lead (600-Mil) Molded DIP	Commercial
	CY7C130-35PI	P25	48-Lead (600-Mil) Molded DIP	Industrial
	CY7C130-35DMB	D26	48-Lead (600-Mil) Sidebraze DIP	Military
45	CY7C130-45PC	P25	48-Lead (600-Mil) Molded DIP	Commercial
	CY7C130-45PI	P25	48-Lead (600-Mil) Molded DIP	Industrial
	CY7C130-45DMB	D26	48-Lead (600-Mil) Sidebraze DIP	Military
55	CY7C130-55PC	P25	48-Lead (600-Mil) Molded DIP	Commercial
	CY7C130-55PI	P25	48-Lead (600-Mil) Molded DIP	Industrial
	CY7C130-55DMB	D26	48-Lead (600-Mil) Sidebraze DIP	Military
15	CY7C131-15JC	J69	52-Lead Plastic Leaded Chip Carrier	Commercial
	CY7C131-15JXC	J69	52-Lead Pb-Free Plastic Leaded Chip Carrier	
	CY7C131-15NC	N52	52-Pin Plastic Quad Flatpack	
	CY7C131-15JI	J69	52-Lead Plastic Leaded Chip Carrier	Industrial
	CY7C131-15JXI	J69	52-Lead Pb-Free Plastic Leaded Chip Carrier	
25	CY7C131-25JC	J69	52-Lead Plastic Leaded Chip Carrier	Commercial
	CY7C131-25JXC	J69	52-Lead Pb-Free Plastic Leaded Chip Carrier	
	CY7C131-25NC	N52	52-Pin Plastic Quad Flatpack	
	CY7C131-25NXC	N52	52-Pin Pb-Free Plastic Quad Flatpack	
	CY7C131-25JI	J69	52-Lead Plastic Leaded Chip Carrier	Industrial
	CY7C131-25NI	N52	52-Pin Plastic Quad Flatpack	
30	CY7C131-30JC	J69	52-Lead Plastic Leaded Chip Carrier	Commercial
	CY7C131-30NC	N52	52-Pin Plastic Quad Flatpack	
	CY7C131-30JI	J69	52-Lead Plastic Leaded Chip Carrier	Industrial
35	CY7C131-35JC	J69	52-Lead Plastic Leaded Chip Carrier	Commercial
	CY7C131-35NC	N52	52-Pin Plastic Quad Flatpack	
	CY7C131-35JI	J69	52-Lead Plastic Leaded Chip Carrier	Industrial
	CY7C131-35NI	N52	52-Pin Plastic Quad Flatpack	
45	CY7C131-45JC	J69	52-Lead Plastic Leaded Chip Carrier	Commercial
	CY7C131-45NC	N52	52-Pin Plastic Quad Flatpack	
	CY7C131-45JI	J69	52-Lead Plastic Leaded Chip Carrier	Industrial
	CY7C131-45NI	N52	52-Pin Plastic Quad Flatpack	
55	CY7C131-55JC	J69	52-Lead Plastic Leaded Chip Carrier	Commercial
	CY7C131-55JXC	J69	52-Lead Pb-Free Plastic Leaded Chip Carrier	7
	CY7C131-55NC	N52	52-Pin Plastic Quad Flatpack	7
	CY7C131-55NXC	N52	52-Pin Pb-Free Plastic Quad Flatpack	1
	CY7C131-55JI	J69	52-Lead Plastic Leaded Chip Carrier	Industrial
	CY7C131-55JXI	J69	52-Lead Pb-Free Plastic Leaded Chip Carrier	1
	CY7C131-55NI	N52	52-Pin Plastic Quad Flatpack	7

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Ordering Information (continued)

Speed (ns)	Ordering Code	Package Name	Package Type	Operating Range
30	CY7C140-30PC	P25	48-Lead (600-Mil) Molded DIP	Commercial
	CY7C140-30PI	P25	48-Lead (600-Mil) Molded DIP	Industrial
35	CY7C140-35PC	P25	48-Lead (600-Mil) Molded DIP	Commercial
	CY7C140-35PI	P25	48-Lead (600-Mil) Molded DIP	Industrial
	CY7C140-35DMB	D26	48-Lead (600-Mil) Sidebraze DIP	Military
45	CY7C140-45PC P25	48-Lead (600-Mil) Molded DIP	Commercial	
	CY7C140-45PI	P25	48-Lead (600-Mil) Molded DIP	Industrial
	CY7C140-45DMB	D26	48-Lead (600-Mil) Sidebraze DIP	Military
55	CY7C140-55PC	P25	48-Lead (600-Mil) Molded DIP	Commercial
	CY7C140-55PI	P25	48-Lead (600-Mil) Molded DIP	Industrial
	CY7C140-55DMB	D26	48-Lead (600-Mil) Sidebraze DIP	Military
15	CY7C141-15JC	J69	52-Lead Plastic Leaded Chip Carrier	Commercial
	CY7C141-15NC	N52	52-Pin Plastic Quad Flatpack	
25	CY7C141-25JC	J69	52-Lead Plastic Leaded Chip Carrier	Commercial
	CY7C141-25JXC	J69	52-Lead Pb-Free Plastic Leaded Chip Carrier	
	CY7C141-25NC	N52	52-Pin Plastic Quad Flatpack	
	CY7C141-25JI	J69	52-Lead Plastic Leaded Chip Carrier	Industrial
	CY7C141-25NI	N52	52-Pin Plastic Quad Flatpack	7
30	CY7C141-30JC	J69	52-Lead Plastic Leaded Chip Carrier	Commercial
	CY7C141-30NC	N52	52-Pin Plastic Quad Flatpack	
	CY7C141-30JI	J69	52-Lead Plastic Leaded Chip Carrier	Industrial
35	CY7C141-35JC	J69	52-Lead Plastic Leaded Chip Carrier	Commercial
	CY7C141-35NC	N52	52-Pin Plastic Quad Flatpack	7
	CY7C141-35JI	J69	52-Lead Plastic Leaded Chip Carrier	Industrial
	CY7C141-35NI	N52	52-Pin Plastic Quad Flatpack	7
45	CY7C141-45JC	J69	52-Lead Plastic Leaded Chip Carrier	Commercial
	CY7C141-45NC	N52	52-Pin Plastic Quad Flatpack	7
	CY7C141-45JI	J69	52-Lead Plastic Leaded Chip Carrier	Industrial
	CY7C141-45NI	N52	52-Pin Plastic Quad Flatpack	
55	CY7C141-55JC	J69	52-Lead Plastic Leaded Chip Carrier	Commercial
	CY7C141-55NC	N52	52-Pin Plastic Quad Flatpack	
	CY7C141-55JI	J69	52-Lead Plastic Leaded Chip Carrier	Industrial
	CY7C141-55NI	N52	52-Pin Plastic Quad Flatpack	



MILITARY SPECIFICATIONS

Group A Subgroup Testing

DC Characteristics

Parameter	Subgroups
V _{OH}	1, 2, 3
V _{OL}	1, 2, 3
V _{IH}	1, 2, 3
V _{IL} Max.	1, 2, 3
I _{IX}	1, 2, 3
I _{OZ}	1, 2, 3
I _{CC}	1, 2, 3
I _{SB1}	1, 2, 3
I _{SB2}	1, 2, 3
I _{SB3}	1, 2, 3
I _{SB4}	1, 2, 3

Switching Characteristics

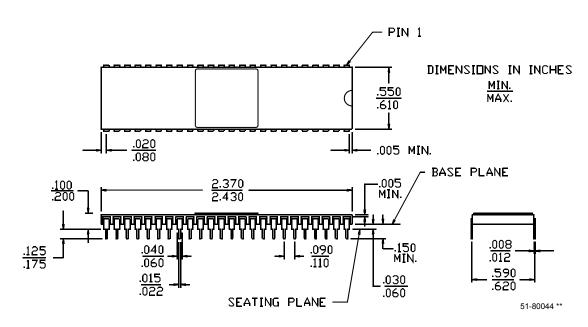
Parameter	Subgroups			
READ CYCLE				
t _{RC}	7, 8, 9, 10, 11			
t _{AA}	7, 8, 9, 10, 11			
t _{ACE}	7, 8, 9, 10, 11			
t _{DOE}	7, 8, 9, 10, 11			
WRITE CYCLE				
t_{WC}	7, 8, 9, 10, 11			
t _{SCE}	7, 8, 9, 10, 11			
t _{AW}	7, 8, 9, 10, 11			
t _{HA}	7, 8, 9, 10, 11			
t _{SA}	7, 8, 9, 10, 11			
t _{PWE}	7, 8, 9, 10, 11			
t _{SD}	7, 8, 9, 10, 11			
t _{HD}	7, 8, 9, 10, 11			
BUSY/INTERRUPT TIMING				
t _{BLA}	7, 8, 9, 10, 11			
t _{BHA}	7, 8, 9, 10, 11			
t _{BLC}	7, 8, 9, 10, 11			
t _{BHC}	7, 8, 9, 10, 11			
t _{PS}	7, 8, 9, 10, 11			
t _{WINS}	7, 8, 9, 10, 11			
t _{EINS}	7, 8, 9, 10, 11			
t _{INS}	7, 8, 9, 10, 11			
t _{OINR}	7, 8, 9, 10, 11			
t _{EINR}	7, 8, 9, 10, 11			
t _{INR}	7, 8, 9, 10, 11			
BUSY TIMING				
t _{WB} ^[24]	7, 8, 9, 10, 11			
t _{WH}	7, 8, 9, 10, 11			
t _{BDD}	7, 8, 9, 10, 11			

Note: 24. CY7C140/CY7C141 only.

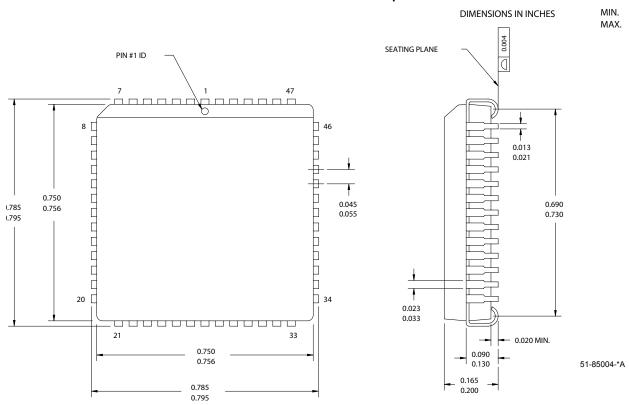


Package Diagrams

48-Lead (600-Mil) Sidebraze DIP D26MIL-STD-1835 D-14 Config. C



52-Lead Plastic Leaded Chip Carrier J69 52-Lead Pb-Free Plastic Leaded Chip Carrier J69

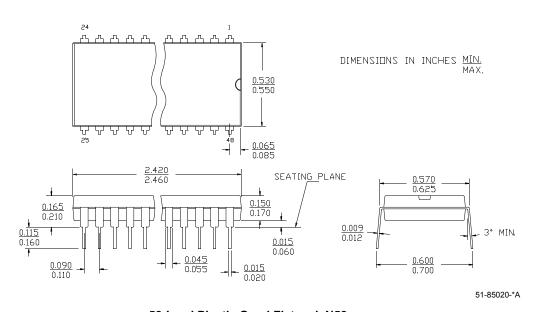


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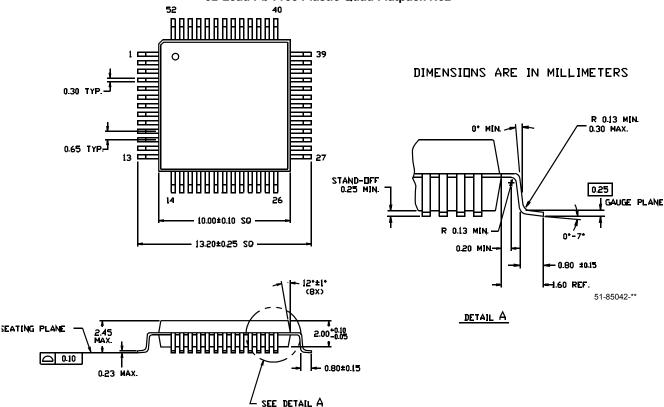


Package Diagrams (continued)

48-Lead (600-Mil) Molded DIP P25



52-Lead Plastic Quad Flatpack N52 52-Lead Pb-Free Plastic Quad Flatpack N52



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Document History Page

REV.	ECN NO.	Issue Date	Orig. of Change	Description of Change
**	110169	09/29/01	SZV	Change from Spec number: 38-00027 to 38-06002
*A	122255	12/26/02	RBI	Power up requirements added to Maximum Ratings Information
*B	236751	See ECN	YDT	Removed cross information from features section
*C	325936	See ECN	RUY	Added pin definitions table, 52-pin PQFP package diagram and Pb-free information
*D	393153	See ECN	YIM	Added CY7C131-15JI to ordering information Added Pb-Free parts to ordering information: CY7C131-15JXI